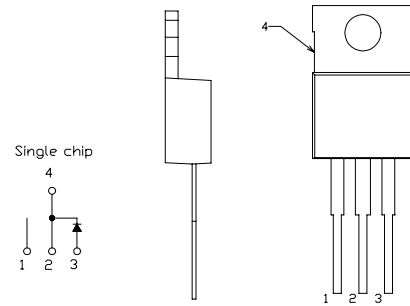


SBD Type : GSH10A10B

OUTLINE DRAWING

FEATURES

- *Similar to TO-220AB Case
- *Low Forward Voltage Drop
- *Low Power Loss,High Efficiency
- *High Surge Capability
- *T_j=150 °C operation



Maximum Ratings

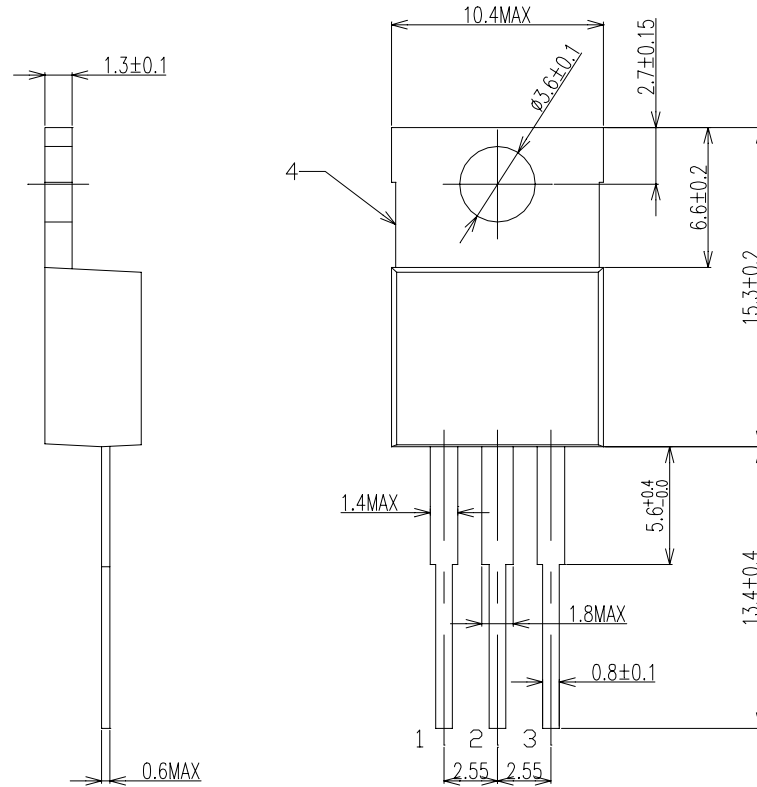
Approx Net Weight: 1.9g

Rating	Symbol	GSH10A10B			Unit
Repetitive Peak Reverse Voltage	V _{RRM}	100			V
Average Rectified Output Current	I _O	10	Tc=120°C	50 Hz half Sine Wave Resistive Load	A
RMS Forward Current	I _{F(RMS)}	15.7			A
Surge Forward Current	I _{FSM}	180	50Hz Half Sine Wave ,1cycle Non-repetitive		A
Operating JunctionTemperature Range	T _{jw}	-40 to +150			°C
Storage Temperature Range	T _{stg}	-40 to +150			°C
Mounting torque	F _{tor}	recommended torque = 0.5			N•m

Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I _{RM}	T _j = 25°C, V _{RM} = V _{RRM}	-	-	1	mA
Peak Forward Voltage	V _{FM}	T _j = 25°C, I _{FM} = 10 A	-	-	0.88	V
Thermal Resistance	R _{th(j-c)}	Junction to Case	-	-	3	°C /W

GSH10A10B OUTLINE DRAWING (Dimention in mm)



Single chip

